**Engineered Quantum States in Graphene Nanoribbons**

Oliver Gröning, Shiyong Wang1, Qiang Sun, Pascal Ruffieux and Roman Fasel

Empa, Swiss Federal Laboratories for Materials Science and Technology,
8600 Dübendorf, Switzerland

(Corresponding author: O. Gröning, e-mail: oliver.groening@empa.ch)
1School of Physics and Astronomy, Shanghai Jiao Tong University, Shanghai, China

Graphene provides an ideal platform to create materials with diverse electronic properties by rational control of its nanoscale structure. Quantum confinement effects can be exploited in strictly planar 2D (e.g. porous graphene) or 1D (graphene nanoribbon GNR) graphene structures. However, in order to achieve well defined electronic properties with high electron motilities the nanostructures need to be synthetized with atomic precision [1].

Very recently, it has been found theoretically that localized zero energy modes can be obtained at the junctions of topologically dissimilar graphene nanoribbons (GNR) [2]. We have experimentally realized such GNR junctions using on-surface synthesis, i.e. by the polymerization of molecular precursors rationally designed to yield the desired final GNR on single crystal surfaces. By creating well defined periodic sequences of these topological electronic modes, one-dimensional electronic bands can be created, which are described by the Su-Schrieffer-Heeger (SSH) Hamiltonian representing the dimerized atomic chain. By manipulating the intra- and inter-cell coupling strength we could further create SSH analogues with different Chern number and therefore topological class. The topological class distinction is evidenced by presence, respectively absence of zero energy end states at the termini of the corresponding GNR or their junctions to structurally dissimilar GNRs.

Figure 1: Figure can be included in the abstract

We will discuss the concept of topological boundary states in GNR junctions and the creation of 1D SSH-type electronic bands by their periodic arrangement on a host GNR. The theoretical basis of attributing Z2 topological invariants to these structures will be discussed. We then present the experimental synthesis of different structures exhibiting different topological classes. The structural characterization and atomic precision of these GNR was achieved by low-temperature scanning tunneling microscopy (STM) and high resolution non-contact atomic force microscopy (nc-AFM). The electronic properties are elucidated by scanning tunneling spectroscopy (STS), where we invoke the bulk-boundary correspondence to determine the topological properties [3].

Support by the Swiss National Science Foundation is gratefully acknowledged.

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